ROHS

HALOGEN

FREE



Vishay General Semiconductor

High Current Density Surface Mount Schottky Barrier Rectifiers



DO-220AA (SMP)

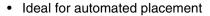
PRIMARY CHARACTERISTICS				
I _{F(AV)}	2.0 A			
V _{RRM}	50 V, 60 V			
I _{FSM}	50 A			
E _{AS}	11.25 mJ			
V _F	0.54 V			
T _J max.	150 °C			

TYPICAL APPLICATIONS

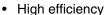
For use in low voltage high frequency inverters, freewheeling, dc-to-dc converters and polarity protection applications.

FEATURES

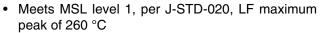
• Very low profile - typical height of 1.1 mm



Low forward voltage drop, low power losses



Low thermal resistance



Solder dip 265 °C max. 10 s, per JESD 22-A111

 Compliant to RoHS directive 2002/95/EC and in accordance to WEEE 2002/96/EC

Halogen-free according to IEC 61249-2-21 definition

MECHANICAL DATA

Case: DO-220AA (SMP)

Molding compound meets UL 94 V-0 flammability

rating

Base P/N-M3 - halogen-free and RoHS compliant,

commercial grade

Base P/NHM3 - halogen-free and RoHS compliant,

AEC-Q101 qualified

Terminals: Matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 1A whisker test, HM3 suffix meets JESD 201 class 2 whisker test

Polarity: Color band denotes the cathode end

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)					
PARAMETER	SYMBOL	SS2P5	SS2P6	UNIT	
Device marking code		25	26		
Maximum repetitive peak reverse voltage	V _{RRM}	50	60	V	
Maximum average forward rectified current (Fig. 1)	I _{F(AV)}	2.0		А	
Peak forward surge current 10 ms single half sine-wave superimposed on rated load	I _{FSM}	50		А	
Non-repetitive avalanche energy at I_{AS} = 1.5 A, L = 10 mH, T_J = 25 °C	E _{AS}	11.25		mJ	
Voltage rate of change (rated V _R)	dV/dt	10 000		V/µs	
Operating junction and storage temperature range	T _{J,} T _{STG}	- 55 to + 150			

SS2P5 & SS2P6

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ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)							
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT	
Maximum instantaneous forward voltage (1)	I _F = 2 A I _F = 2 A	T _J = 25 °C T _J = 125 °C	V _F	0.62 0.54	0.70 0.60	V	
Maximum reverse current at rated V _R ⁽²⁾		T _J = 25 °C T _J = 125 °C	I _R	1.6	100 10	μA mA	
Typical junction capacitance	4.0 V, 1 MHz		CJ	80		pF	

Notes:

- (1) Pulse test: 300 µs pulse width, 1 % duty cycle
- (2) Pulse test: Pulse width ≤ 40 ms

THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise specified)						
PARAMETER	SYMBOL	SS2P5	SS2P6	UNIT		
Typical thermal resistance ⁽¹⁾	$egin{array}{l} R_{ hetaJA} \ R_{ hetaJL} \ R_{ hetaJC} \end{array}$	115 15 20		°C/W		

Note:

(1) Thermal resistance from junction to ambient and junction to lead mounted on P.C.B. with 5.0 x 5.0 mm copper pad areas. $R_{\theta JL}$ is measured at the terminal of cathode band. $R_{\theta JC}$ is measured at the top centre of the body

ORDERING INFORMATION (Example)					
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE	
SS2P5-M3/84A	0.024	84A	3000	7" diameter plastic tape and reel	
SS2P5-M3/85A	0.024	85A	10 000	13" diameter plastic tape and reel	
SS2P5HM3/84A (1)	0.024	84A	3000	7" diameter plastic tape and reel	
SS2P5HM3/85A (1)	0.024	85A	10 000	13" diameter plastic tape and reel	

Note:

(1) AEC-Q101 qualified

RATINGS AND CHARACTERISTICS CURVES

 $(T_A = 25 \, ^{\circ}C \text{ unless otherwise noted})$

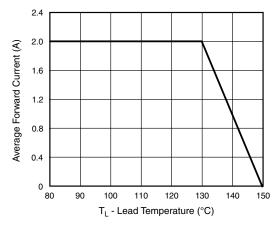


Figure 1. Forward Current Derating Curve

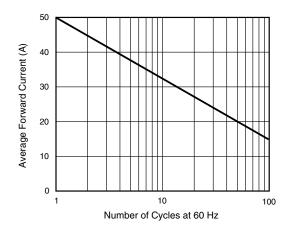


Figure 2. Maximum Non-Repetitive Peak Forward Surge Current



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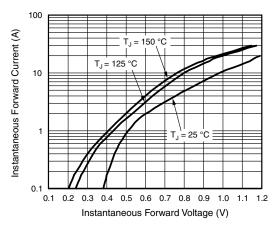


Figure 3. Typical Instantaneous Forward Characteristics

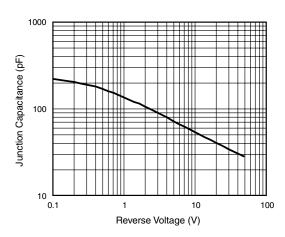


Figure 5. Typical Junction Capacitance

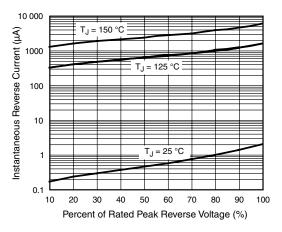


Figure 4. Typical Reverse Leakage Characteristics

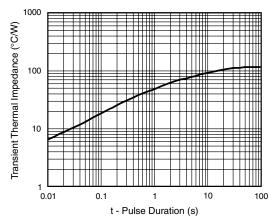
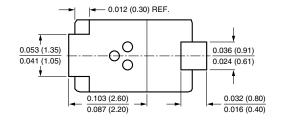
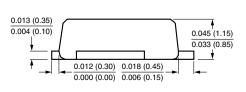


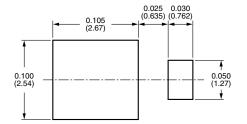
Figure 6. Typical Transient Thermal impedance

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

0.086 (2.18) 0.074 (1.88) 0.142 (3.61) 0.126 (3.19) 0.158 (4.00) 0.146 (3.70)







DO-220AA (SMP)



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